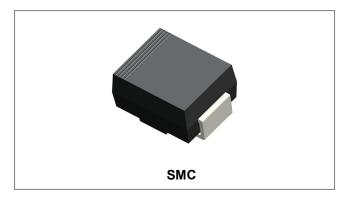






# ER3A-ER3J SURFACE MOUNT SUPER FAST RECTIFIER



#### **Features**

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Overload Drop, High Efficiency
- Low Power Loss
- Super-Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



#### **Mechanical Data**

- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.23grams(approx)

## Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Characteristic	Symbol	ER3A	ER3B	ER3C	ER3D	ER3E	ER3G	ER3J	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	150	200	300	400	600	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	105	140	210	280	420	
Average Rectified Output Current @TL =75°C	lo	3.0				Α			
Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	100				Α			
Forward Voltage @I <sub>F</sub> = 3.0A, T <sub>J</sub> =25°C	V <sub>F</sub>			0.95		1.25	5	1.7	V
Maximum DC reverse current T <sub>A</sub> = 25°C at rated DC blocking voltage T <sub>A</sub> = 125°C	I <sub>R</sub>	5.0 100			μA				
Typical junction capacitance (Note 1)	Сл	45			pF				
Maximum Reverse Recovery Time (Note 2)	Trr	35			ns				
Typical thermal resistance (Note 3)	R <sub>0</sub> JL	16			°C/W				
Operating junction and storage temperature range	$T_J, T_{STG}$	-65 to +150			°C				

Note: 1. Measured at 1.0 MHZ and applied reverse voltage of 4.0  $V_{DC}$ 

- 2. Measured with I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>rr</sub>=0.25A,
- 3. Mounted on P.C. Board with 8.0mm2 lead area
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## **Ratings and Characteristics Curves**

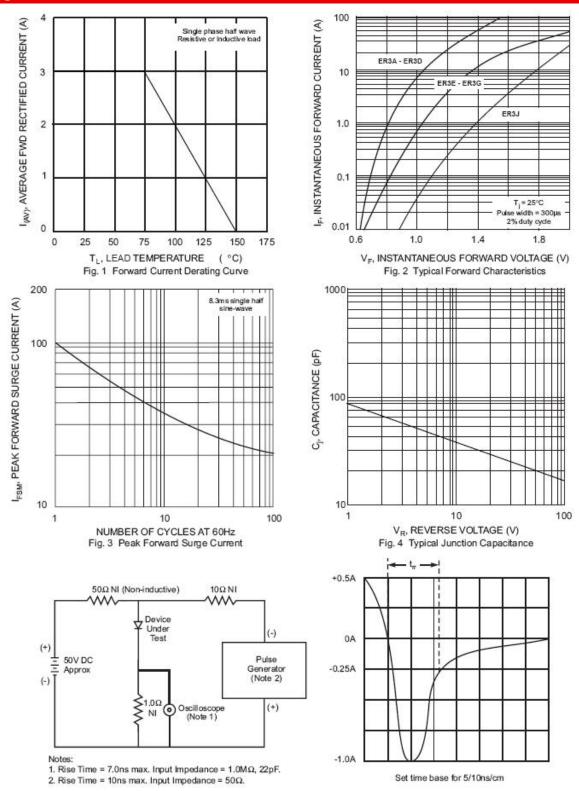


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

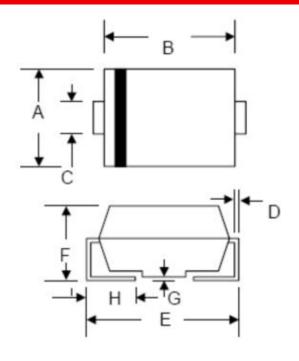
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### **Mechanical Dimensions SMC**



SYMBOL	Millin	neters	Inches			
STWIBOL	Min. Max.		Min.	Max.		
Α	5.59	6.22	0.220	0.245		
В	6.60	7.11	0.260	0.280		
С	2.75	3.25	0.108	0.128		
D	0.152	0.305	0.006	0.012		
E	7.75	8.25	0.305	0.325		
F	2.00	2.95	0.079	0.116		
G	0.051	0.203	0.002	0.008		
Н	0.76	1.60	0.030	0.063		

# **Ordering Information**

Device	Package	Shipping		
ER3A-ER3J	SMC (Pb-Free)	3000pcs / reel		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**



Where XXXXX is YYWWL

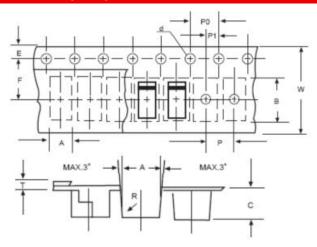
ER = Device Type 3 = Forward Current (3A) A = Reverse Voltage (50V) YY = Year

YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

# **Carrier Tape Specification SMC**



SYMBOL	Millimeters			
STWIDUL	Min.	Max.		
Α	5.90	6.10		
В	8.20	8.40		
C	2.40	2.60		
d	1.40	1.60		
E	1.40	1.60		
F	7.60	7.70		
Р	7.90	8.10		
P0	3.90	4.10		
P1	3.90	4.10		
Т	-	0.600		
W	15.80	16.20		

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